

Modeling of Hydrogen Interactions with Helium Bubbles in Tungsten



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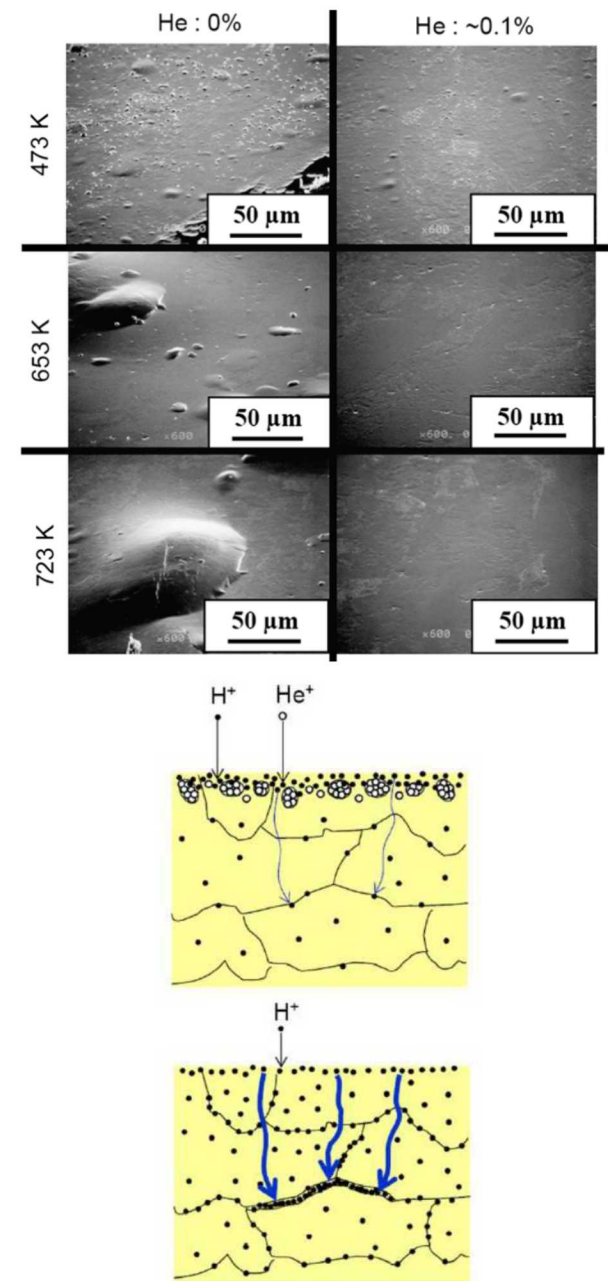


Outline

- Motivation
- Subsurface Mixed H-He Bubble Simulations
 - Methods
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- Large-scale W-H-He Simulations
 - Methods
 - W-H-He Results
- Experimental Results
- Conclusions

Motivation

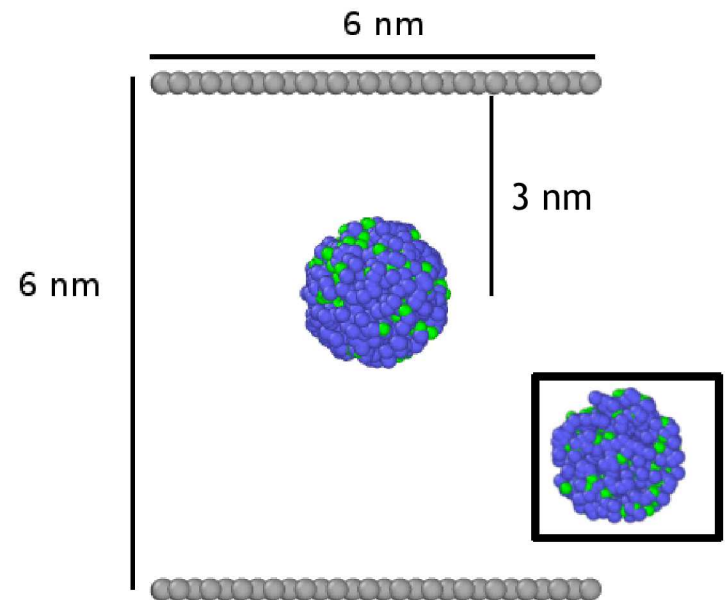
- Tungsten is a candidate material for the divertor of ITER and other future fusion reactors
- Divertor will be subject to high temperatures and particle fluxes of both hydrogen and helium
- Under hydrogen implantation, micron sized blisters on the surface have been observed
- The presence of helium in the plasma, under simultaneous or subsequent helium-hydrogen irradiation, suppresses blisters
- It is hypothesized that the helium bubble layer prevents hydrogen from diffusing deeper into the material to form blisters, but could more strongly trap hydrogen
- Here, we describe MD simulations to investigate He-H synergies in W



Subsurface Mixed H-He Bubble Methods

- 6 nm x 6 nm x 6 nm simulation cell
- Cavity first created with a 1 nm radius and located 3 nm below the surface
- Concentrations of 3, 3.5, or 4 He/V and 0.5 or 1 H/V are randomly distributed within the bubble
- Simulation evolved for 100 ps and diffusion of hydrogen is assessed
- Temperatures of 1200 K, 1500 K, 1800 K, and 2000 K
- (110) and (111) surface orientations
- Tersoff bond order potential for W-H interactions developed by Juslin et al. [1] and modified for H₂ desorption by Guterl et al. [2]

Blue: Helium
Green: Hydrogen
Grey: Tungsten



Initial simulation setup with inset image of a slice through the bubble

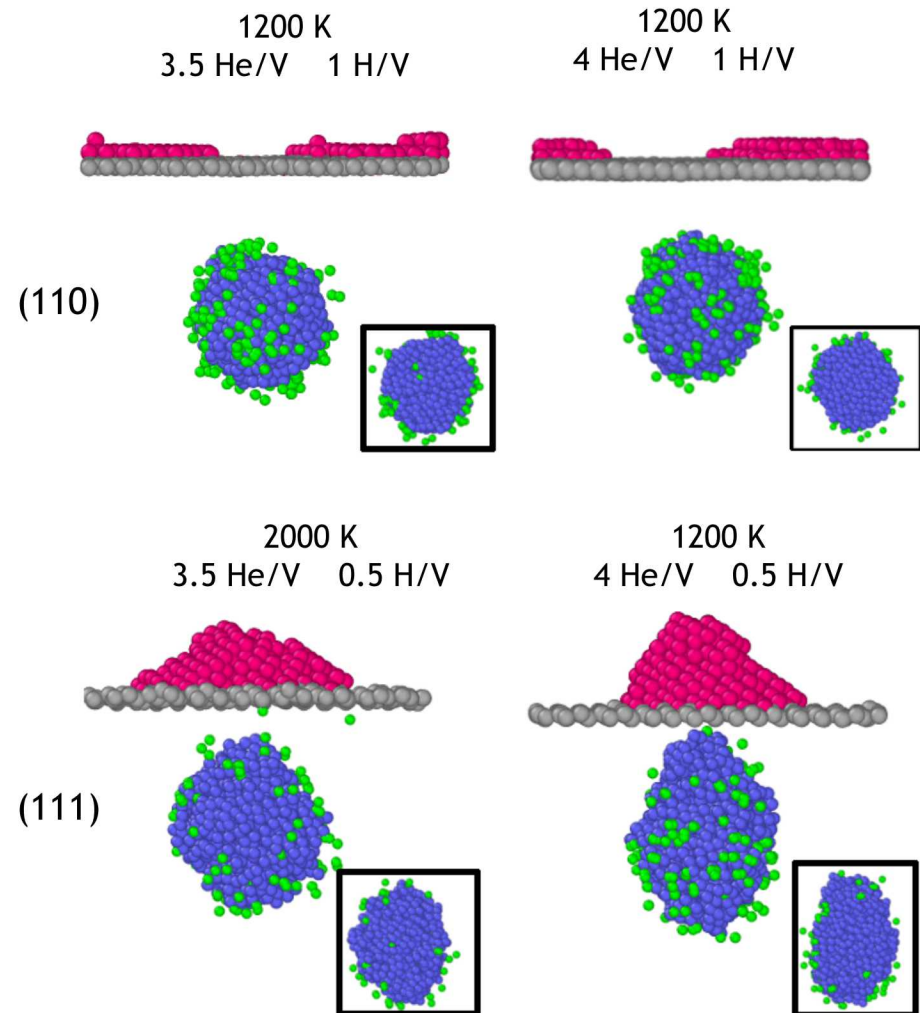
[1] N. Juslin, et al., J. Applied Physics. 98, 123520 (2005)

[2] J. Guterl, et al., J. Nucl. Mater. 463, 263-267 (2015)

Atomistic Snapshots after 100 ps

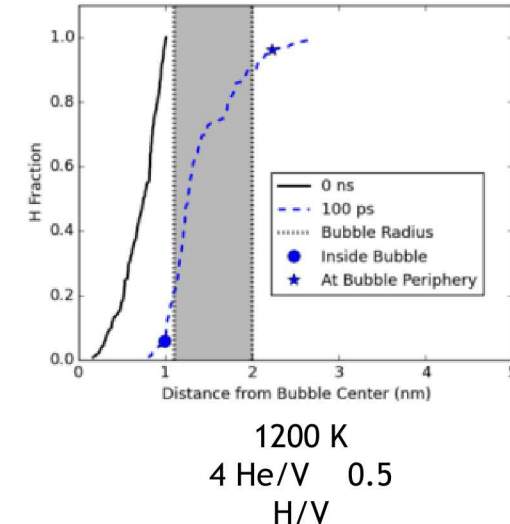
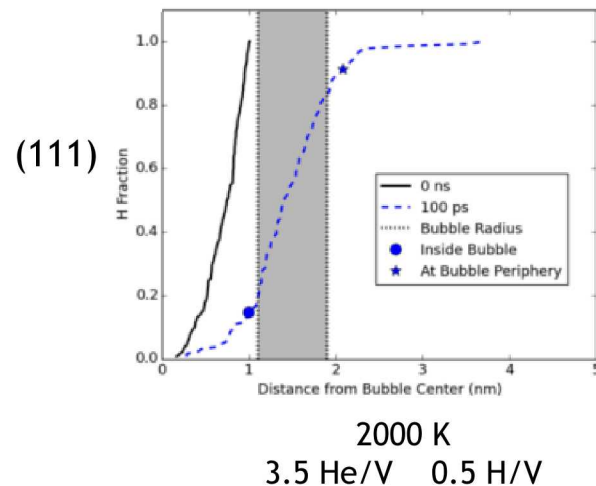
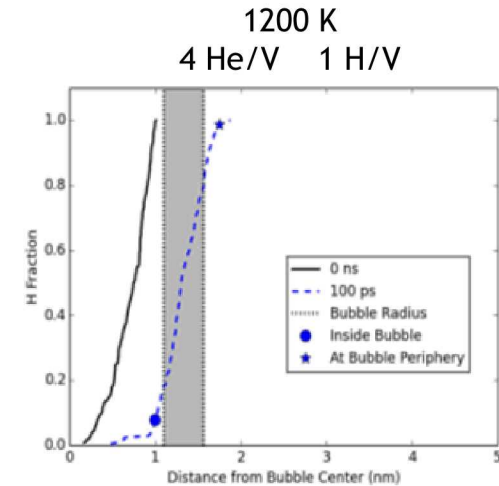
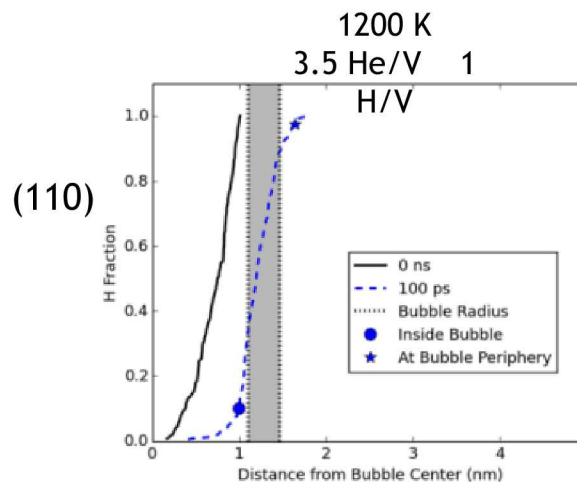
- Initially over-pressurized bubble leads to expansion
- Bubble expansion and loop punching produces adatom formations consistent with previous MD work of helium bubbles
- Expansion occurs within first few ps
- More surface deformation and faster loop punching at higher temperatures and helium concentrations
- Bubble evolution independent of hydrogen
- Adatom/surface patterning depends on surface orientation
- Significant diffusion of hydrogen to helium bubble periphery
- Hydrogen segregation to the bubble edges is observed for all simulations regardless of initial parameters

Blue: Helium Green: Hydrogen
Grey: Tungsten Magenta: Tungsten Adatoms



Hydrogen Cumulative Radial Distributions

- Plots of H distribution from bubble center
- Black line is at 0 ps and blue is at 100 ps
- Gray bar represents range of bubble radius due to non-isotropic expansion
- Circle and star represent hydrogen in the bubble and at the periphery respectively
- Large portion of hydrogen is located at the bubble periphery, $\sim 75\text{-}95\%$ ($17\text{-}22 \text{ H/nm}^3$)
- Typically less than 20% remains in the bubble interior and is mostly H_2
- Standoff distance between helium bubble and tungsten matrix creates excess volume that could be a low energy site for hydrogen, which prefers vacancy-like defects

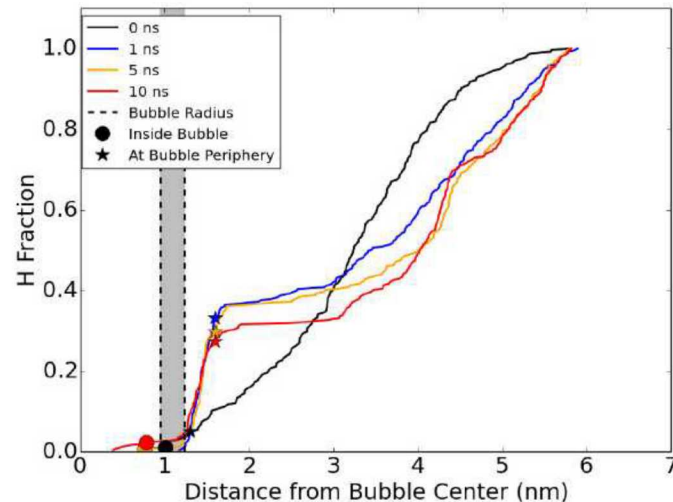
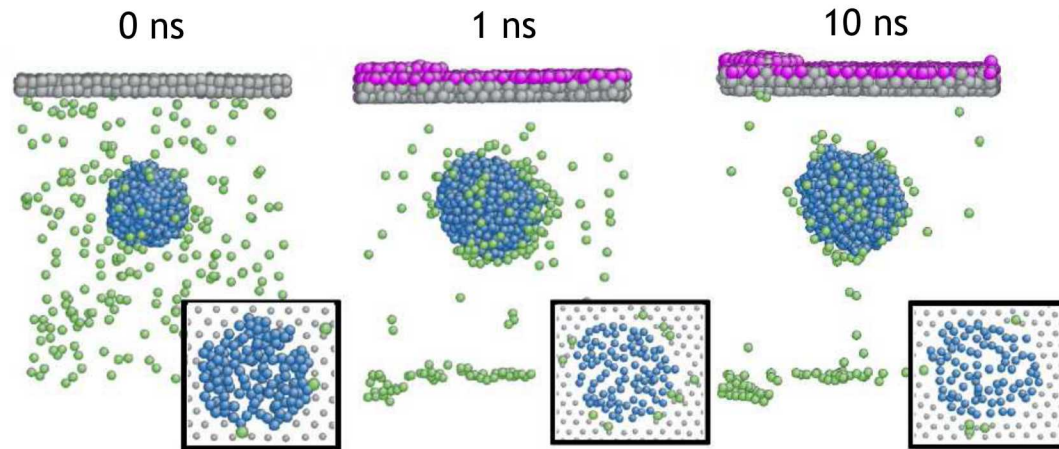


Placing the H Initially Throughout the Box

- Initially place hydrogen randomly throughout the simulation cell
- Simulation run for 10 ns to allow enough time for hydrogen to diffuse
- Hydrogen still diffuses to bubble periphery, ~25-40% of total inventory depending on initial temperature
- Hydrogen very rapidly accumulates at the bubble periphery within first nanosecond and remains there for rest of simulation
- Additional hydrogen at either top or bottom surface
- Hydrogen concentration at bubble periphery higher than at the surface, 4.5 H/nm³ vs. 1.5 H/nm³

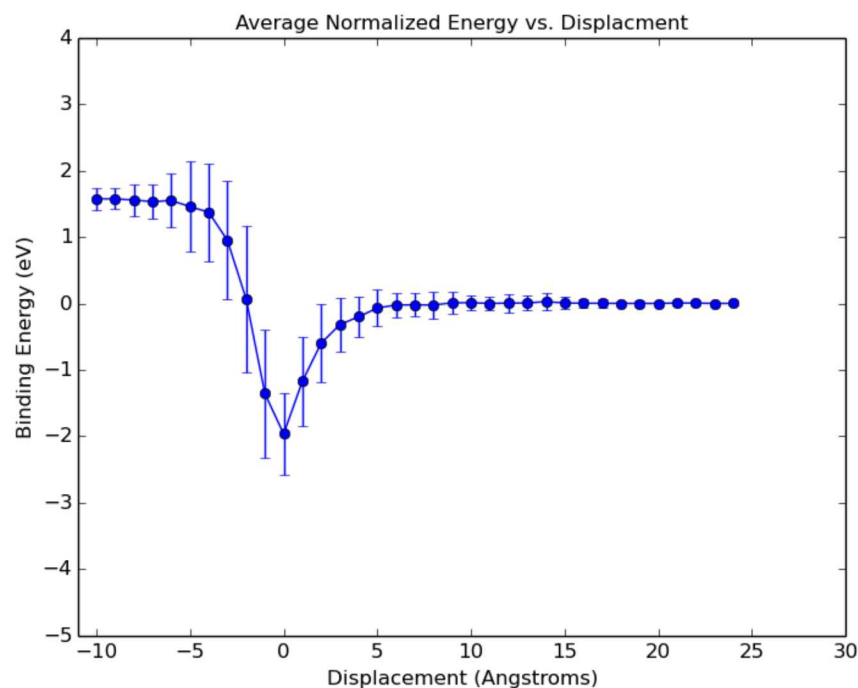
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(110) Surface at 1800 K and 3 He/V and 1 H/V



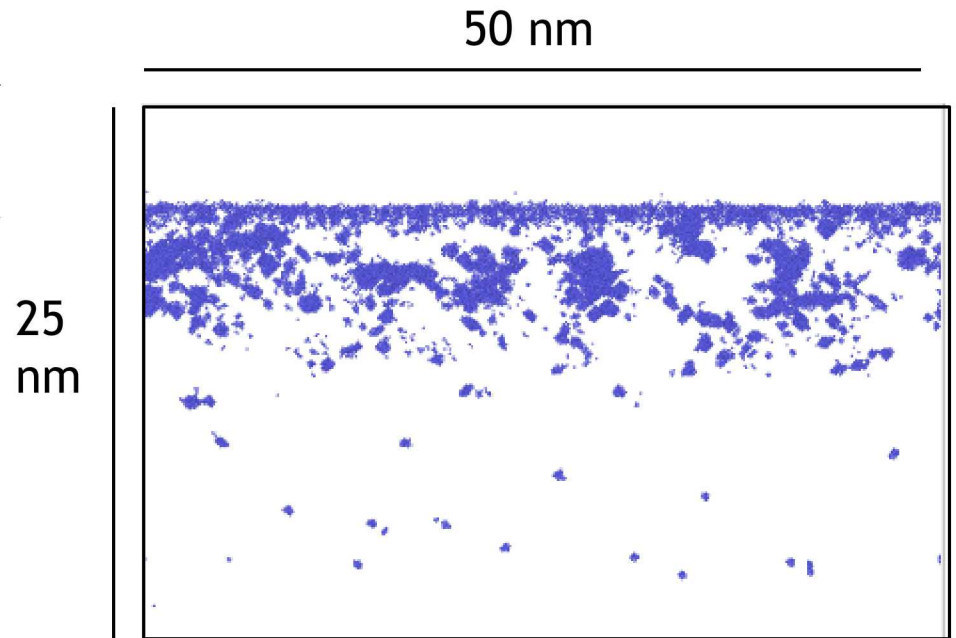
Binding/Trapping Energy Calculations

- Simulations quenched and minimized after 100 ps
- Hydrogen atoms around the bubble are then moved in 1 Å steps, both towards and away from the bubble, and the energy is minimized and recorded
- The energy at each step is normalized to the energy in the bulk and plotted for ~100 hydrogen atoms from 20 different simulations
- There is a clear trapping location at the bubble periphery with a binding energy of 1.5-2.5 eV. The high energy within the helium bubble itself will drive the hydrogen out of the bubble
- Moving hydrogen into the the bubble is repulsive
- A binding energy of ~2 eV and an activation energy of ~0.3 eV (migration energy of interstitial H), implies desorption temperatures > 1000 K -- the energy needed to overcome this potential well could be as high as ~2.3 eV



Large Scale Hydrogen and Hydrogen-Helium Modeling

- Large scale 50 nm x 50 nm x 25 nm box with a free surface in the z direction
- ~4 million tungsten atoms with initial helium implantation to a fluence of $\sim 10^{19} \text{ m}^{-2}$
- Hydrogen implanted at thermal energy based on 60 eV depth distribution from SRIM at an effective flux of $\sim 10^{25} \text{ m}^{-2}\text{s}^{-1}$
- Compare hydrogen implantation in pure tungsten and helium irradiated tungsten
- 933 K
- Two different hydrogen potentials compared
 - Tersoff bond order potential for W-H interactions developed by Juslin et al. [1] and modified for H_2 desorption by Guterl et al. [2]
 - EAM W-H potential developed by Wang, et al [3]



Initial He distribution for W-H-He simulations

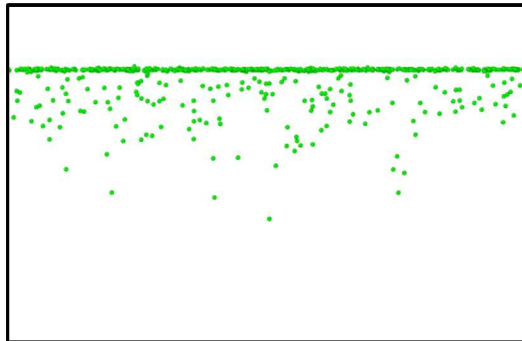
[1] N. Juslin, et al., J. Applied Physics. 98, 123520 (2005)

[2] J. Guterl, et al., J. Nucl. Mater. 463, 263-267 (2015)

[3] XXXX

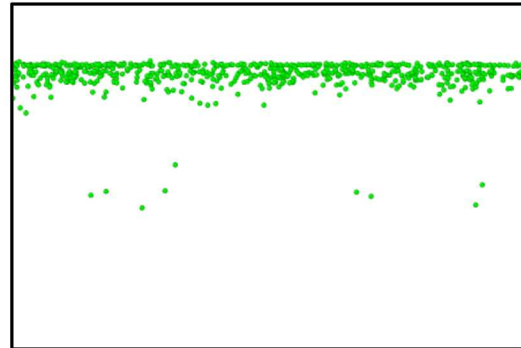
W-H and W-H-He at a fluence of $2.8 \times 10^{17} \text{ m}^{-2}$

Pure Tungsten

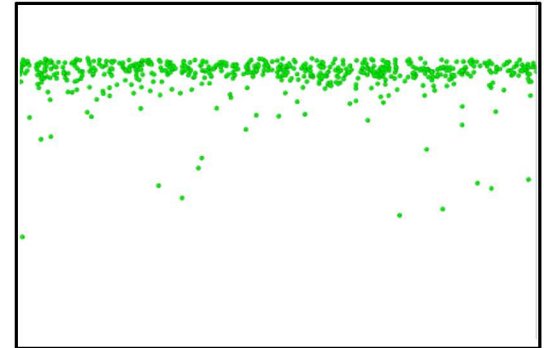


Tersoff

He Irradiated

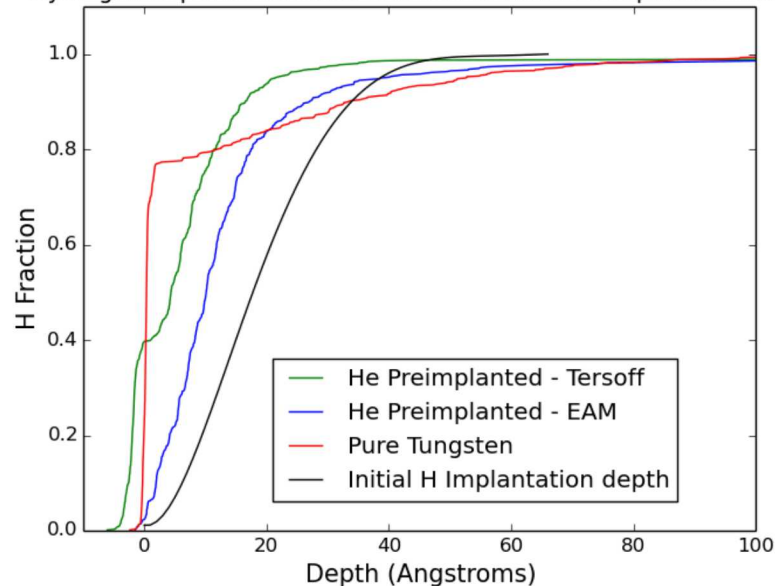


Tersoff



EAM

Hydrogen Depth Distribution with and without Pre-Implanted Helium

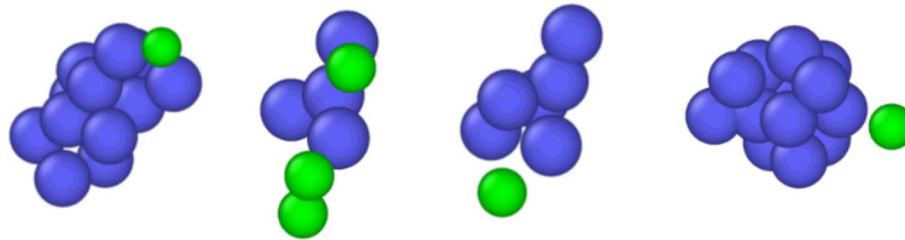


- Hydrogen depth distributions modified in presence of helium
- In pure tungsten case, ~80% of hydrogen is located directly at the surface and some diffuses deeper into the bulk
- In the helium pre-implanted case, the hydrogen is preferentially located in the helium bubble layer 5-10 Angstroms below the surface, about 60% and 80% for the Tersoff and EAM potential respectively
- More hydrogen has diffused deeper in the material for the pure tungsten case. Very few, about ~10 hydrogen atoms, have diffused passed the bubble layer in the pre-implanted cases

H Binding to He Clusters (Observed Clusters from MD)



Snapshots of H - He cluster interactions in MD simulations with pre-implanted He



Blue: Helium
Green: Hydrogen

Hydrogen Binding Energies to Small Clusters		
Cluster Identified Using Tersoff		
Configuration	Tersoff Binding Energy (eV)	EAM Binding Energy (eV)
$He_{40}H_2V_{23}$	0.26	0.25
$He_{16}H_1V_3$	1.71	0.32
$He_{11}H_1V_1$	1.11	0.82
$He_4H_1V_1$	1.48	0.79
Clusters Identified Using EAM		
Configuration	Tersoff Binding Energy (eV)	EAM Binding Energy (eV)
$He_{145}H_1V_{23}$	0.31	0.86
$He_{20}H_1V_4$	1.12	0.93
$He_{19}H_1V_3$	0.63	0.94
$He_9H_1V_1$	0.67	0.28

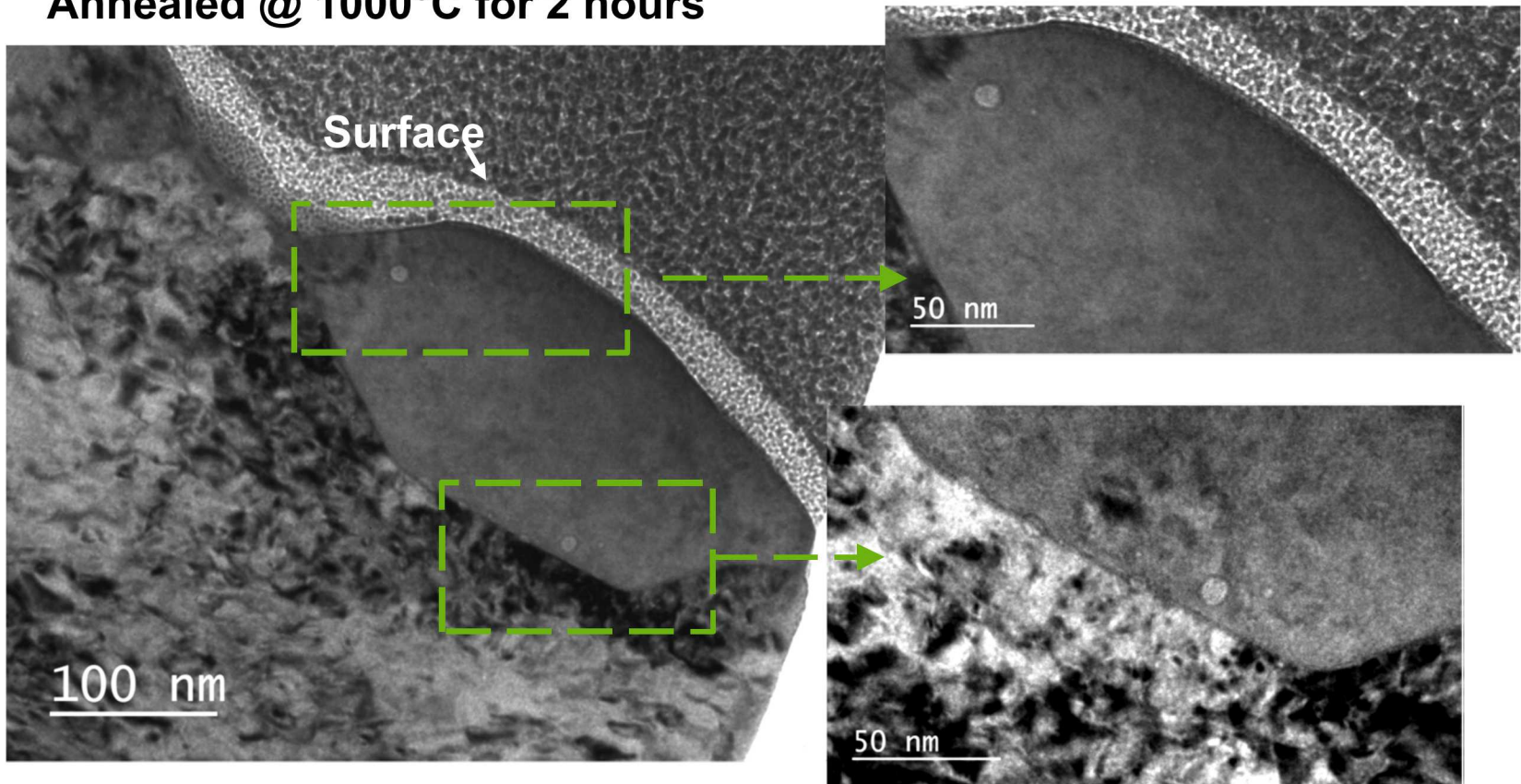
- 37.5% and 60% of the H located in the He bubble layer is located near a helium cluster/bubble for the Tersoff and EAM potential respectively (using a search algorithm & interaction cutoff distance of 0.32 nm)
- Remainder of H is mostly atomic with a few H_2 molecules
- Binding energy tends to be slightly lower with EAM

Planned Experimental Work

- Perform experiments to validate observations from modeling work, namely if helium bubbles will trap hydrogen in tungsten
- Initially perform helium implantations to get the desired microstructure and bubble density
- Subsequently expose the helium implantated tungsten samples to hydrogen using a hydrogen permeation setup being built at ORNL
- Bulk helium implantation and subsequent annealing has been performed at SNL and TEM is currently being utilized to observe bubble distribution.
- In-situ helium implantation and subsequent in-situ annealing was done at SNL to observe bubble growth at different temperatures

Cross-section TEM of the initial bulk helium implanted samples resulted in unexpected results

**700keV He, $5 \times 10^{16}/\text{cm}^2$, RT implantation
Annealed @ 1000°C for 2 hours**

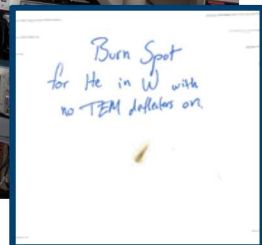
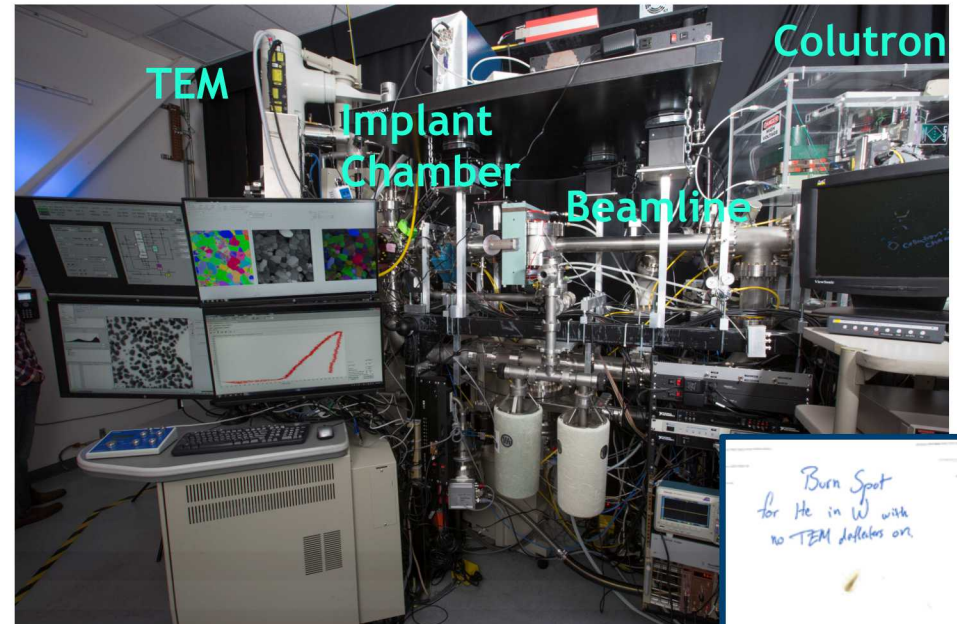
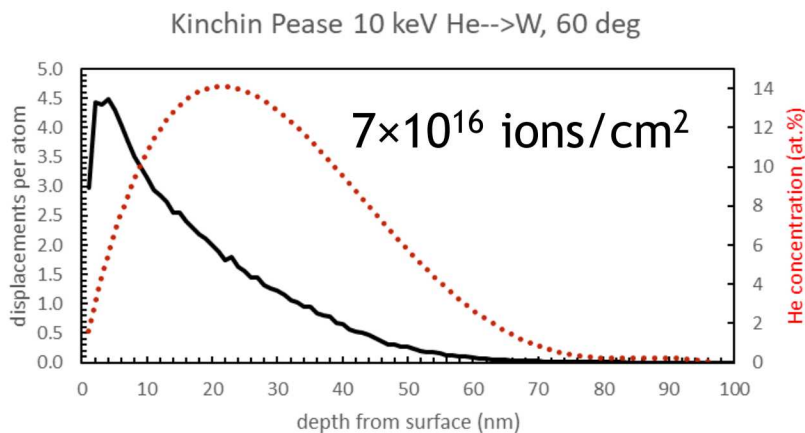


- According to the SRIM simulation, He bubbles should be observed at a depth of 300 nm - 1.4 μm . They were instead only observed at the surface.
- Samples were annealed after implantation, but bubbles were expected to grow in the same region as the initial implantation.

In-situ helium implantation and annealing were used to observe bubble growth and migration kinetics

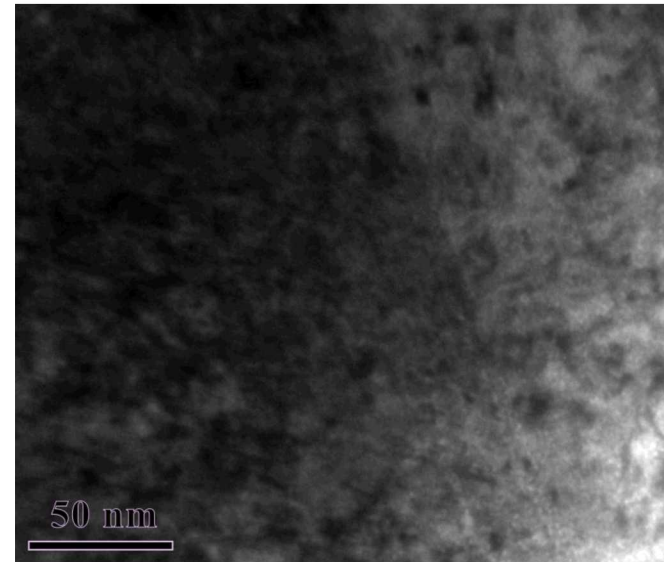
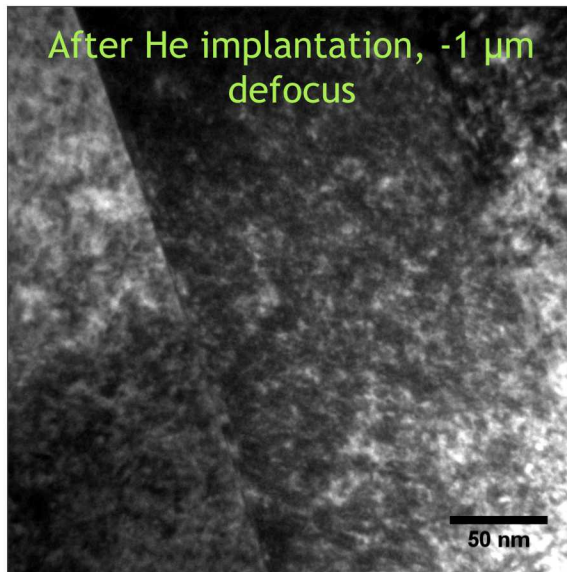
- FIB lift-out of W plate was used for TEM experiments
- He ion flux ranged from 1.29×10^{13} – 7.81×10^{13} ions/cm²/s
- JEOL single tilt stage was used for He implantation and Gatan double tilt heating stage was used for annealing
- During in-situ annealing, due to the high melting temperature of W (3,422°C), the temperature was ramped in 100°C increments. The temperature was held for 5 min at each step until 900°C, when bubble growth was first observed.

Approximate TEM
sample thickness



Bubbles were not observed until annealing at 900°C ($T_h = 0.32$)

- Due to significant FIB & He implantation damage, small bubbles could not be observed during in-situ He implantation
- Small bubbles were eventually observed during annealing at a temperature of 900°C.
 - At this temperature, the FIB damage started to anneal away.
 - Bubbles began to grow, making them easier to observe.
- In some cases, cavities appear to be diffusing through the W and coalescing.
 - Surprising observation at this low of a homologous temperature, but maybe explains bulk results



Conclusions



Subsurface Mixed H-He Bubbles

- Bubble (growth/loop punching) evolution is similar to previous MD results and depends on helium concentration and temperature
- For all cases, the hydrogen diffuses to the bubble periphery, with about 75-95% of the hydrogen located here after 100 ps
- A significant amount of hydrogen diffuses to the bubble periphery, ~25-40%, even when the hydrogen is initially distributed throughout the simulation cell
- The hydrogen at the bubble periphery may be strongly bound, with a binding energy of $\sim 2-2.5$ eV
- These results indicate that helium bubbles may be a significant trapping site for hydrogen, and therefore tritium – although validity of interatomic potentials and short-time MD simulations necessitate further study

Large-scale W-H-He

- When helium and helium bubbles are present, the H depth distribution is modified such that the hydrogen is located within the subsurface helium bubble layer as opposed to directly at the surface
- Helium appears to limit deeper hydrogen diffusion into the material
- For the hydrogen that is in the bubble layer, ~66% is clustered with helium which is consistent with the results from the mixed bubble simulations
- Longer simulation times are needed to further assess these results

Experimental Results

- Experiments planned to investigate H-He interactions in tungsten
- Initial He implantation in tungsten performed and bubbles were observed using TEM after annealing to 900 K
- Subsequent exposure to hydrogen will be performed

Backup Slides

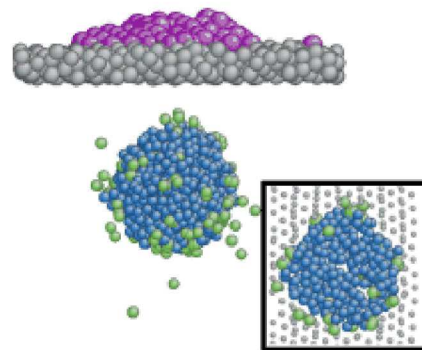
Sensitivity of Simulation Parameters



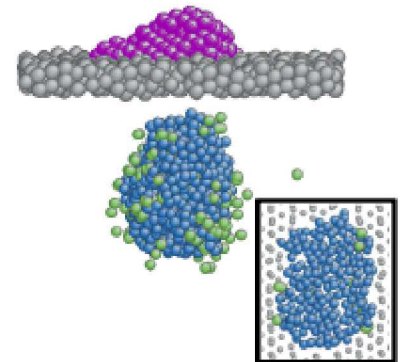
(111) Surface at 1800 K and 3 He/V and 1 H/V

- Extended time
 - Select simulations were run up to 1 ns
 - Some hydrogen starts to diffuse further from the bubble but the majority still remains near the bubble periphery
- Double the tungsten width from 6 nm to 12 nm
 - Changes the areal density of bubbles due to periodic boundary conditions
 - Affects the initial bubble expansion
 - Leads to more destructive surface deformation especially for the (110) surface and higher gas atom concentrations
- Double the depth of the box from 6 nm to 12 nm and the bubble depth from 3 nm to 6 nm
 - Virtually no surface deformation
 - Bubble expands more laterally
 - Does not affect hydrogen partitioning to the bubble periphery

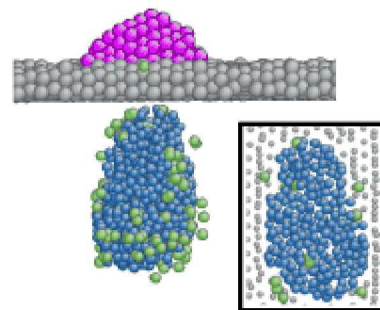
6 nm x 6 nm x 6 nm
100 ps



6 nm x 6 nm x 6 nm
1 ns



12 nm x 12 nm x 6 nm
1 ns



6 nm x 6 nm x 12 nm
1 ns

